	Hit	Search Text	DBs
2	34	coat\$4)) same (resist or photoresist or photosensitive) same (expos\$4 or illuminat\$4 or irradiat\$4)) and ((mask or photomask or reticle) same ((phase near4 shift\$4) or (alternat\$4 near9 phase) or attenuat\$4) same trim\$4)	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB
3	30	photomask or reticle) same ((phase near4 shift\$4) or	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB

	Hit s	Search Text	DBs
4	36	photomask or reticle) same	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB

	Hit s	Search Text	DBs
5	40	photomask or reticle) same ((phase near4 shift\$4) or (alternat\$4 near9 phase) or	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB

	Hit s	Search Text	DBs
6	46	photomask or reticle) same ((phase near4 shift\$4) or	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB

	Hit s	Search Text	DBs
7	149	(alternat\$4 near9 phase) or attenuat\$4)) and ((second or	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB

	Hit s	Search Text	DBs
8	37	((phase near4 shift\$4) or (alternat\$4 near9 phase) or attenuat\$4)) and ((second or third) near6 (mask or reticle or	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB

	Hit s	Search Text	DBs
9	37	<pre>atternat\$4 near9 pnase) or attenuat\$4)) and ((second or third) near6 (mask or reticle or</pre>	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB

	Hit s	Search Text	DBs
10	46	photomask or reticle) same ((phase near4 shift\$4) or	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB

	Hit	Search Text	DBs
11	149	(alternat\$4 near9 phase) or attenuat\$4)) and ((second or	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB
12			US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB
13	5	S12 and ((trim\$4 or reduc\$4) near22 (linewidth or width) near26 (pattern or mask) near22 (resist or photoresist or photosensitive))	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB

	Hit	Search Text	DBs
14	レンち	S12 and ((trim\$4 or reduc\$4) near22 (linewidth or width))	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB
15	49		US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB
16	486	resist or photosensitive) near12	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB
17	170	((first near5 (photoresist or resist or photosensitive) near9 (layer or material or coat\$3 or deposit\$3 or film or form\$3) near22 (expos\$4 or illuminat\$4 or irradiat\$4) near35 (mask or reticle or photomask or phase\$4shift\$4mask or (alternat\$5	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT;